

L Number	Hits	Search Text	DB	Time stamp
1	1650	349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:10
2	1329	349/138	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
3	2268	349/42	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
4	1523	349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
5	1409	349/153	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
6	2	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
7	0	(insult\$6 with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and 349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:12
8	2	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/138	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:12
9	3	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/42	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:12
10	8	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:13
11	0	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/153	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:13
-	1	6344888.pn.	USPAT	2002/11/05 09:54
-	46263	insulat\$6 and moisture	USPAT; JPO	2002/09/10 10:18
-	10402	insulat\$6 with moisture	USPAT; JPO	2002/09/10 10:18
-	43	(insulat\$6 with moisture) and 349/\$.cccls.	USPAT; JPO	2003/05/15 16:47
-	24	(insult\$6 with (silicon adj (nitride or oxide))) and laminat\$5	USPAT; JPO	2002/10/15 14:31
-	34	(insult\$6 with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; JPO	2003/05/15 16:47
-	3883	((insult\$6 or dielectric) same (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; JPO	2002/10/15 14:34
-	3050	((insult\$6 or dielectric) with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; JPO	2002/10/15 14:34

-	36	((insult\$6 or dielectric) near (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and periphery and ((semiconductor or silicon) adj substrate)	USPAT; JPO	2002/10/15 14:40
-	51	((insult\$6 or dielectric) near (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and periphery	USPAT; JPO	2002/10/15 14:39
-	375	((insult\$6 or dielectric) near (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; JPO	2002/10/15 15:11
-	14	((insult\$6 or dielectric) near (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (liquid adj crystal)	USPAT; JPO	2002/10/15 15:12
-	41	("3862360" "3910681" "4024626" "4040727" "4073571" "4103297" "4185894" "4191452" "4239346" "4382658" "4431271" "4470060" "4602850" "4822144" "4839707" "4856019" "5007710" "5056895" "5159476" "5218472" "5254202" "5365355" "5395662" "5461501" "5467216" "5473448" "5497025" "5523862" "5570213" "5648860" "5680231" "5706067" "5760853" "5760981" "5764324" "5798805" "5828493" "5834103" "5838715" "5889570" "5978056").PN.	USPAT	2002/10/15 15:13
-	1	6124912.pn.	USPAT	2002/11/05 09:54
-	63	(insulat\$6 with moisture) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 16:47
-	68	(insult\$6 with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/04 14:12
-	4	(insult\$6 with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation near10 (reflect\$4 metal pixel))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/20 13:31
-	46	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation near10 (reflect\$4 metal pixel))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/04 14:12